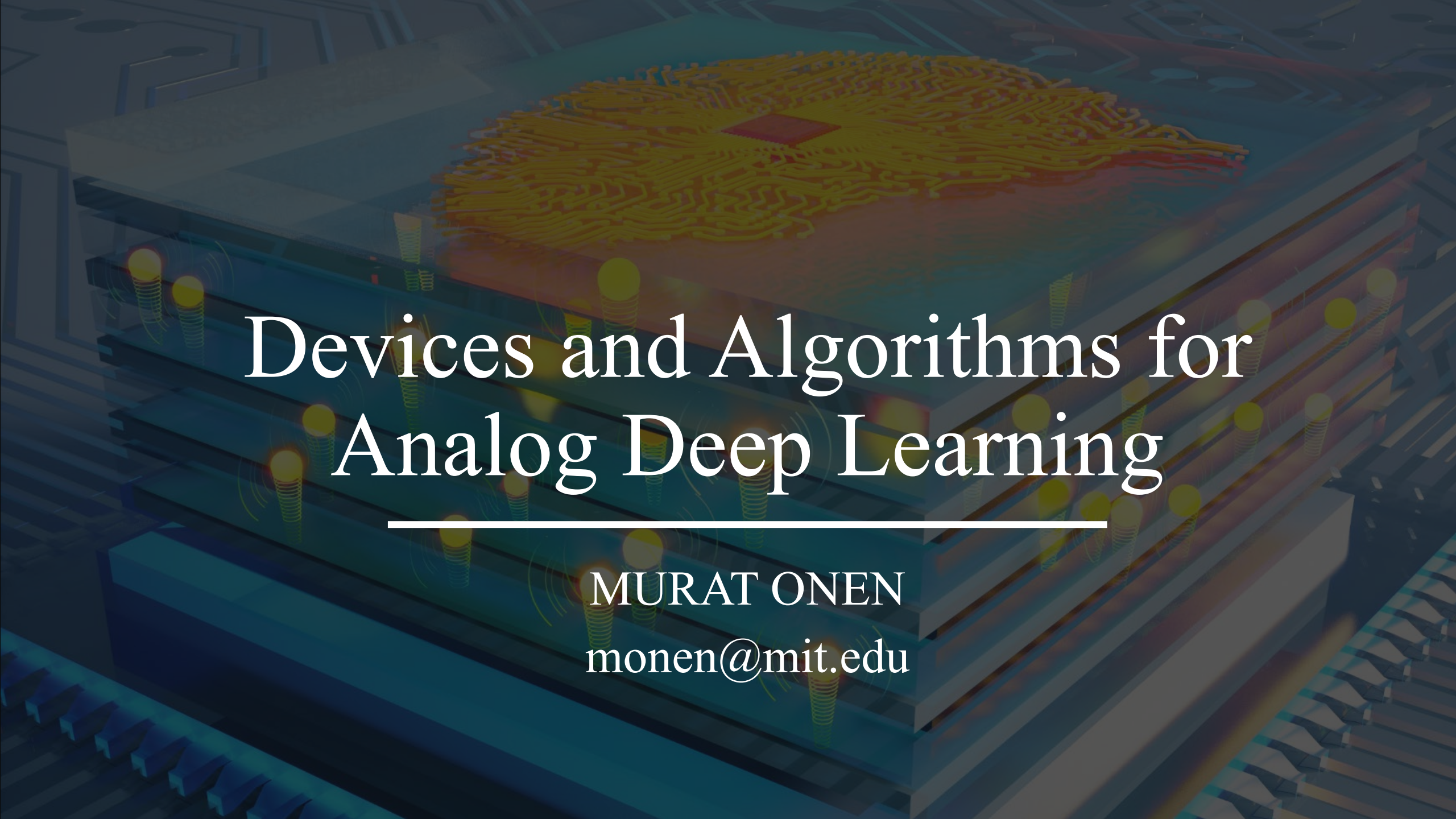
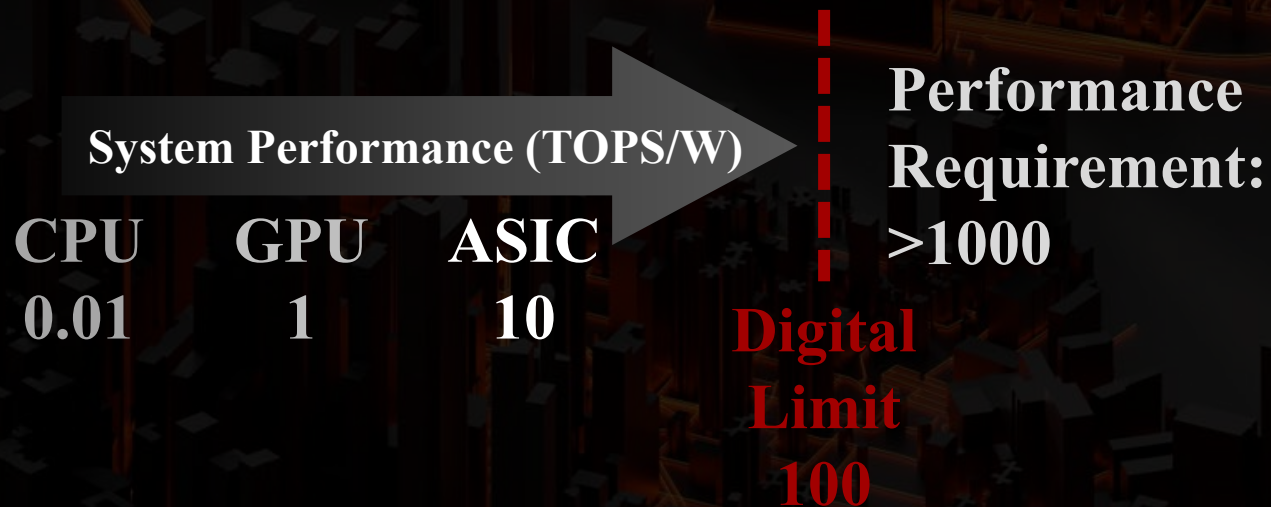




Devices and Algorithms for Analog Deep Learning

MURAT ONEN
monen@mit.edu

Digital Processors are **Insufficient** to Advance AI

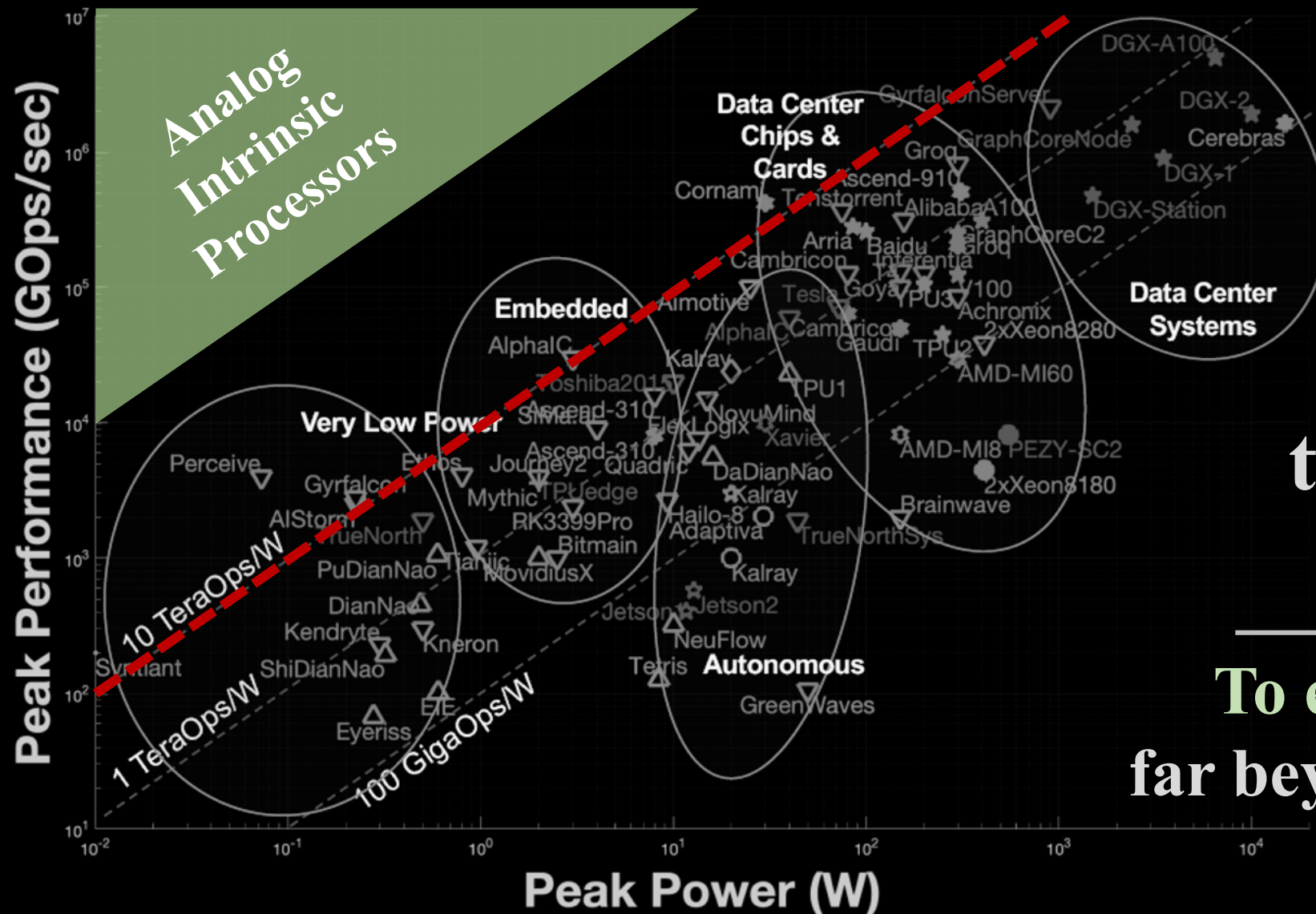


2025 Estimates

\$1B Higher power consumption than
Training cost of one large model. **NYC**

Era-Defining Problem

- ❖ Retail
- ❖ BFSI
- ❖ Manufacturing
- ❖ Marketing
- ❖ Healthcare
- ❖ Automotive
- ❖ Defense
- ❖ Telecom/IT

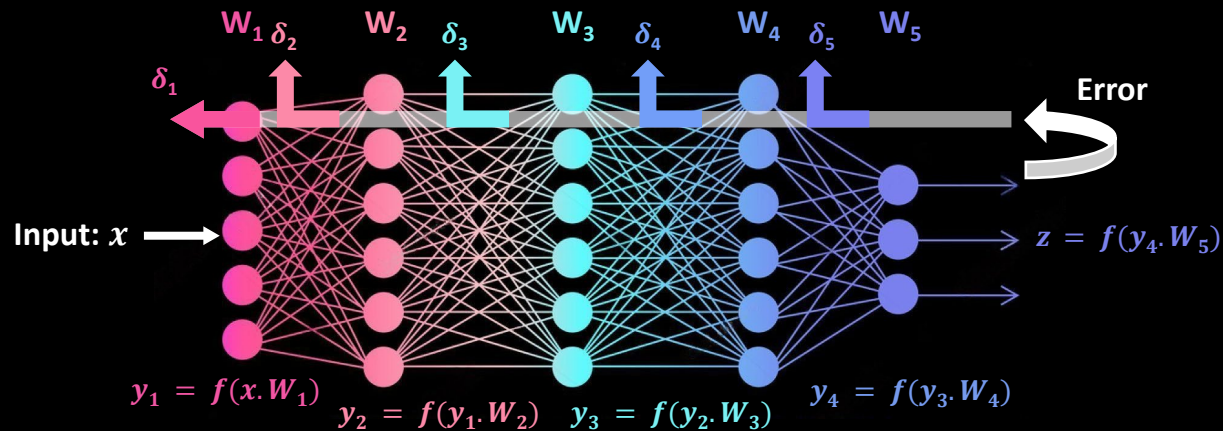


Promising
100× higher
performance
than the leading
digital ASICs.

To enable advanced AI
far beyond current reach.

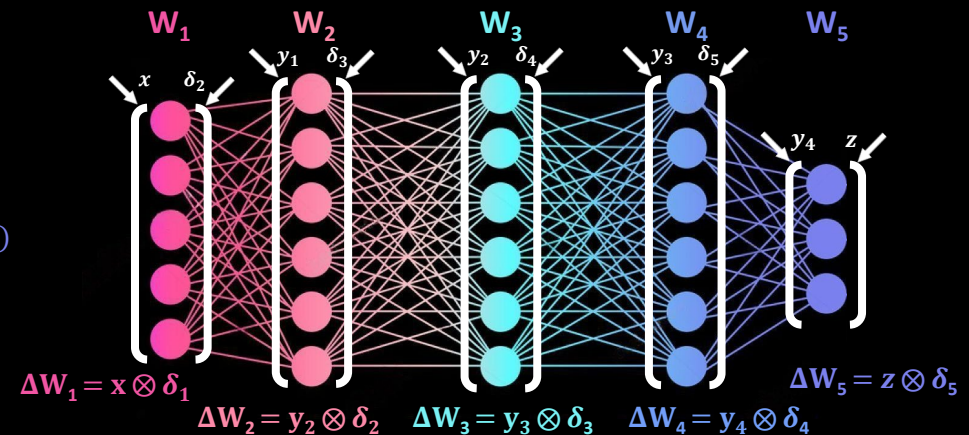
Deep Learning Operations

Testing Inputs
(& Backpropagating Errors)



Matrix Inner Products

Updating Weights

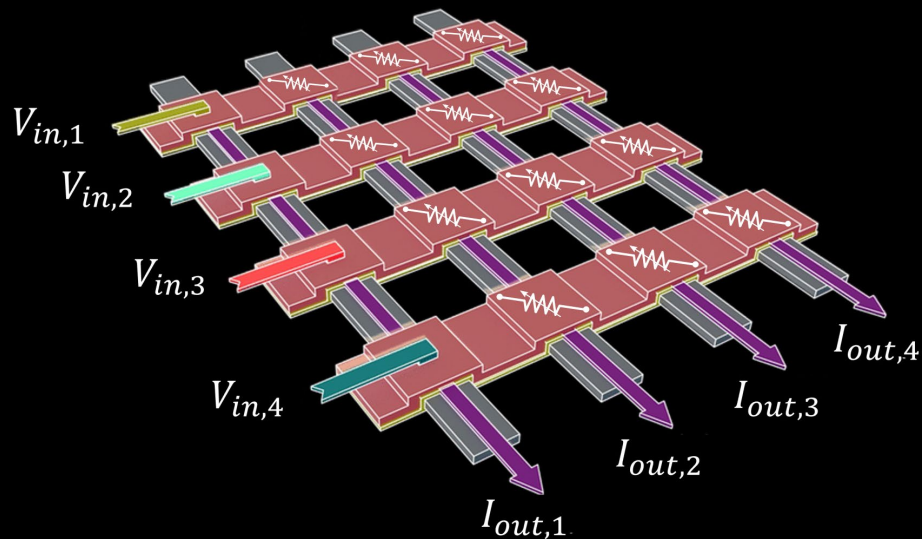


Matrix Outer Products

Need to carry matrices between memory and processor
 $\mathcal{O}(N^3)$ computational complexity

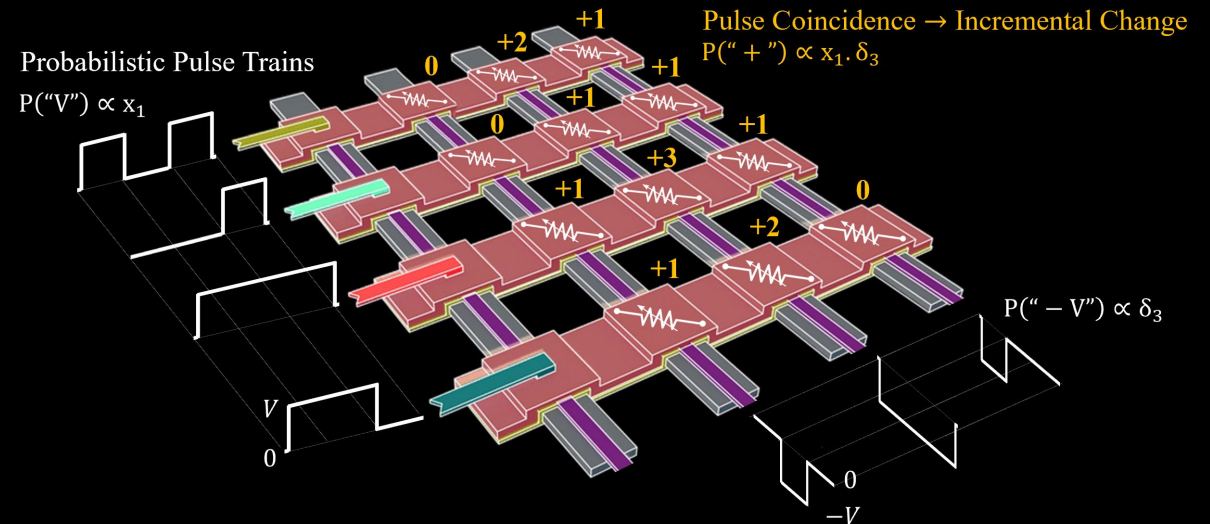
Analog Intrinsic Hardware for Deep Learning Operations

Testing Inputs
(& Backpropagating Errors)



Matrix Inner Products

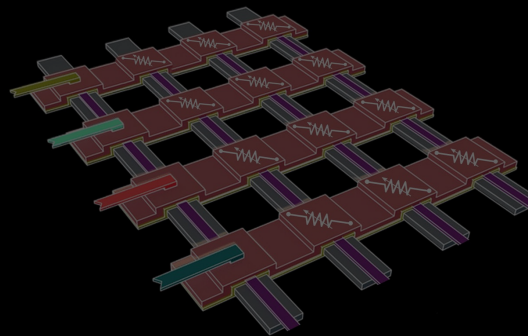
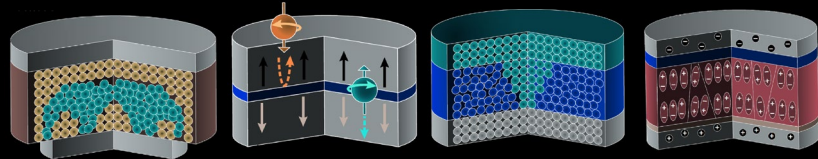
Updating Weights



Matrix Outer Products

Local (in-memory) processing

$\mathcal{O}(N)$ computational complexity (Fully-parallel operation)



- I. $y = Cx$
- II. $z = C^T \delta$
- III. $A \leftarrow A + \eta_A (x \times \delta)$
- IV. $v = Au$
- V. $C \leftarrow C + \eta_C (u \times v)$

Decoupled

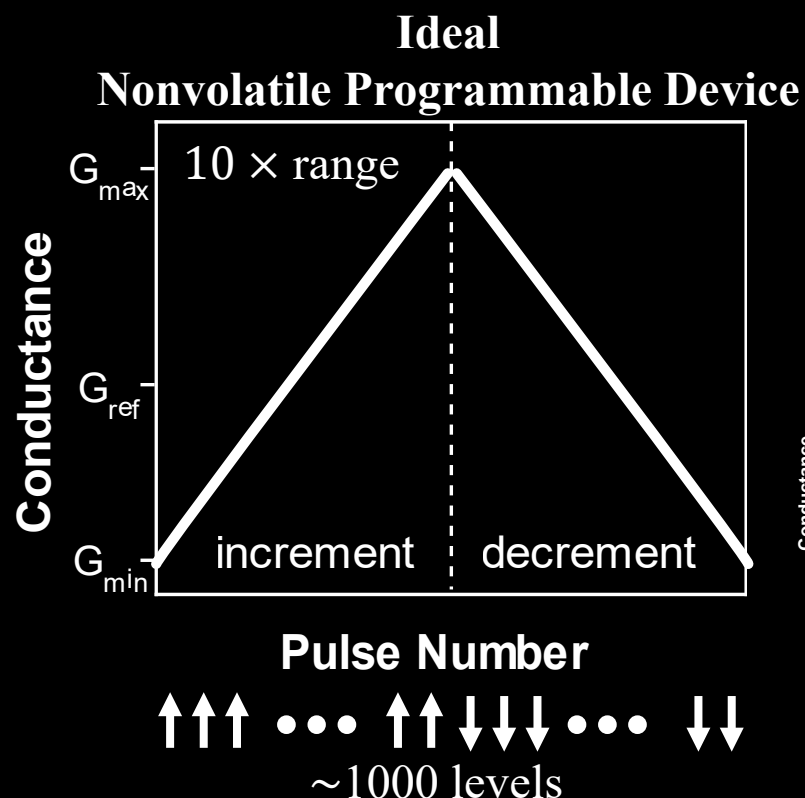
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0 only if $A_{\text{main}} = A_{\text{main,symmetry}}$

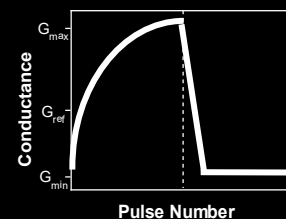
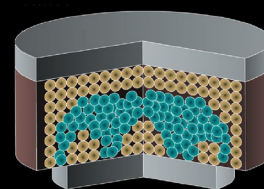
Stable $A \triangleq 0$ when $A_{\text{main}} = A_{\text{main,symmetry}}$

Devices

Algorithms

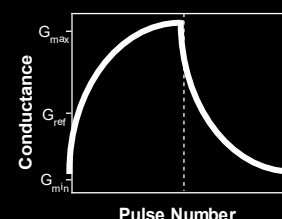
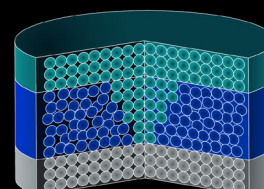


Phase Change Memory



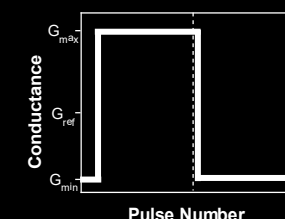
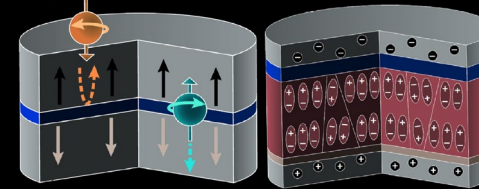
Abrupt Modulation

Filamentary RRAM



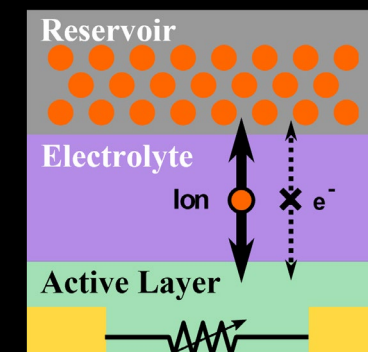
Asymmetric & Stochastic

Magnetic/Ferroelectric RAM

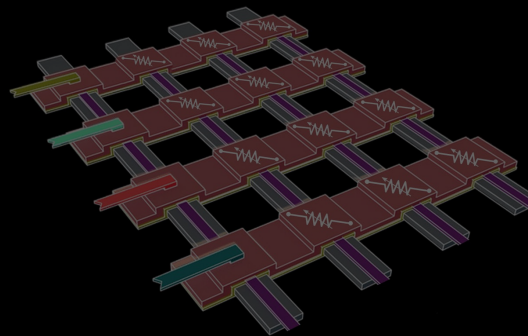
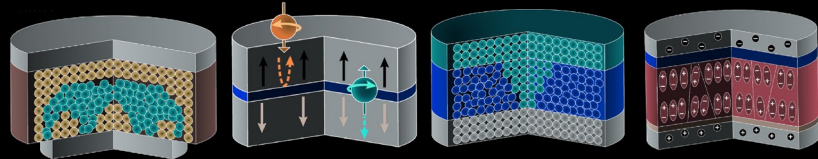


Uncontrollable & Binary

Non-filamentary Ionics



Use ions as dynamic dopants



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Decoupled

$$\begin{aligned} &0 \text{ only if } C = G_0 \\ &\dot{A} = -\eta_A \left[\frac{\partial E}{\partial C} + \epsilon(t) \right] - \kappa_A \eta_A \left[\frac{\partial E}{\partial C} + \epsilon(t) \right] (A_{\text{main}} - A_{\text{main,symmetry}}) \\ &\dot{C} = \eta_C A, \quad E \propto (C - G_0)^2 \end{aligned}$$

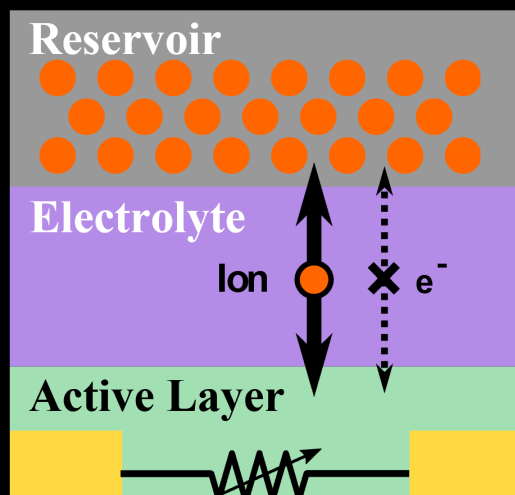
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Stable $A \triangleq 0$ when $A_{\text{main}} = A_{\text{main,symmetry}}$

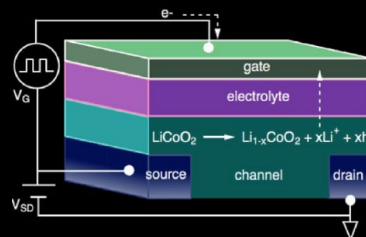
0 only if $A = 0$

Devices

Algorithms

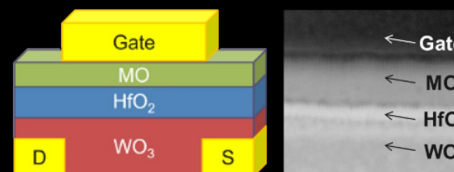


Li⁺ Based



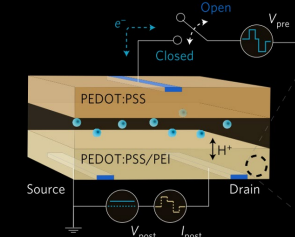
CMOS-
incompatible

O²⁻ Based

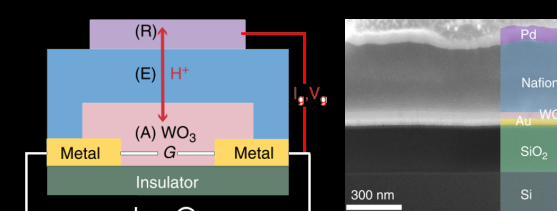


Slow
Energy-inefficient

H⁺ Based



Liquid
Electrolyte

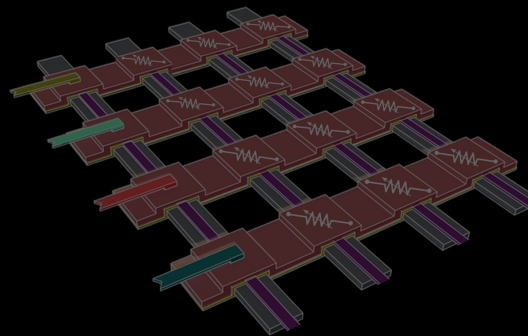
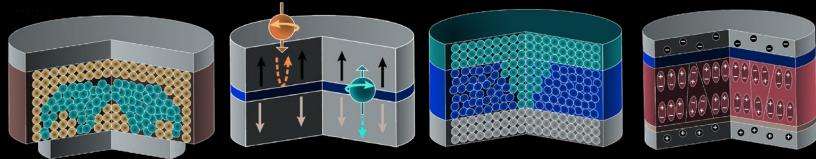


Polymer
Electrolyte

Key Innovation:

Phosphosilicate Glass (PSG, P-SiO₂)

Si-compatible solid-state proton electrolyte



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- II. $z = C^T \delta$
- III. $A \leftarrow A + \eta_A (x \times \delta)$
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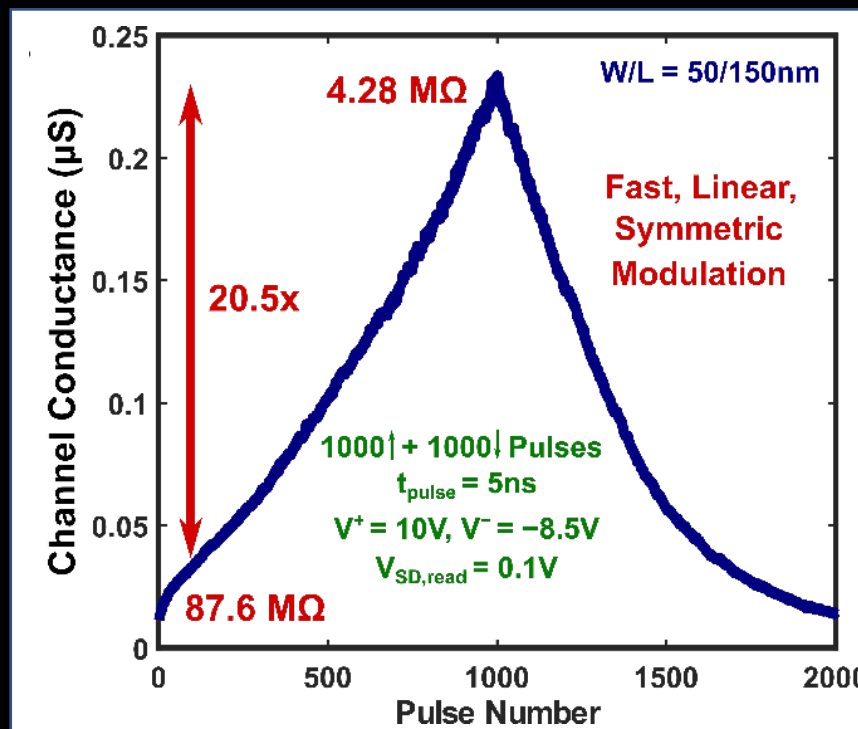
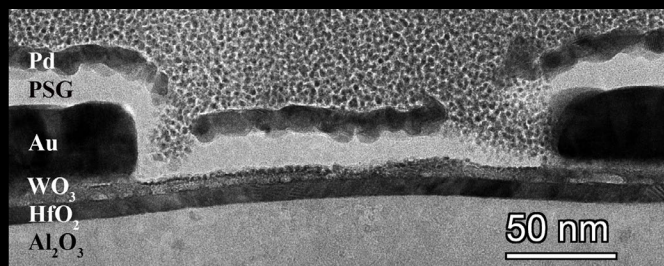
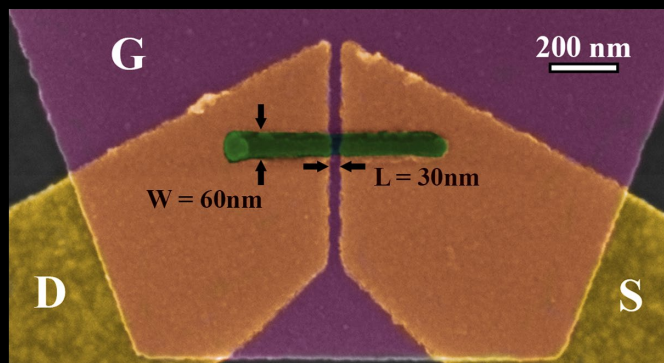
Decoupled

$$\begin{aligned} &0 \text{ only if } C = G_0 \\ &\dot{A} = -\eta_A \left[\frac{\partial E}{\partial C} + \epsilon(t) \right] - \kappa_A \eta_A \left[\frac{\partial E}{\partial C} + \epsilon(t) \right] (A_{\text{main}} - A_{\text{main,symmetry}}) \\ &\dot{C} = \eta_C A, \quad E \propto (C - G_0)^2 \end{aligned}$$

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Devices



Algorithms

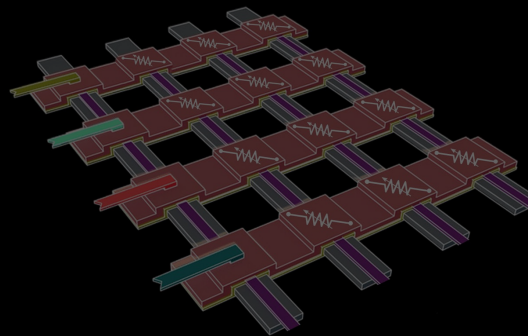
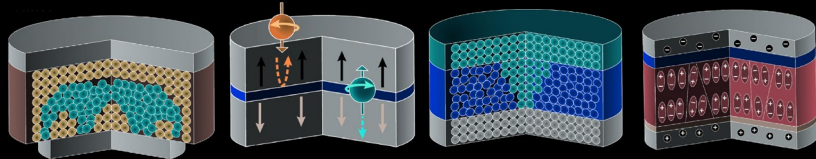
State-of-the-art Combined Properties

- ❖ Si-integration compatible
- ❖ Ultrafast ion transport (5 ns)
- ❖ High energy efficiency (2.5 fJ)
- ❖ Near-ideal modulation
- ❖ 1000 states across 20× range

M. Onen, et al., Nanosecond Protonic Programmable Resistors for Analog Deep Learning, *Science*, (2022).

M. Onen, et al., CMOS-compatible Protonic Programmable Resistor based on Phosphosilicate Glass Electrolyte for Analog Deep Learning, *Nano Letters*, (2021).

M. Onen, et al., Dynamics of PSG-Based Nanosecond Programmable Nanoprotonic Resistors for Analog Deep Learning, *IEDM*, (2022).



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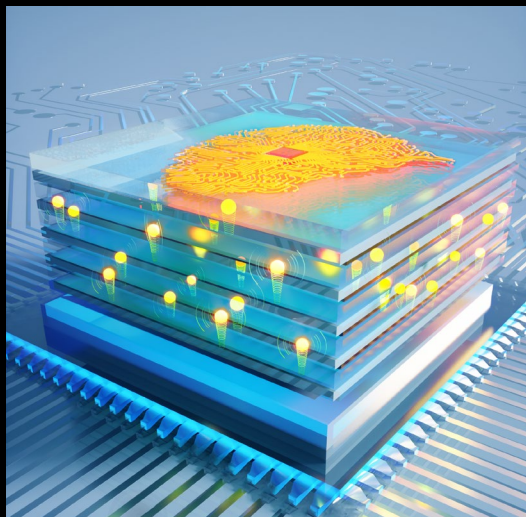
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Devices

Algorithms

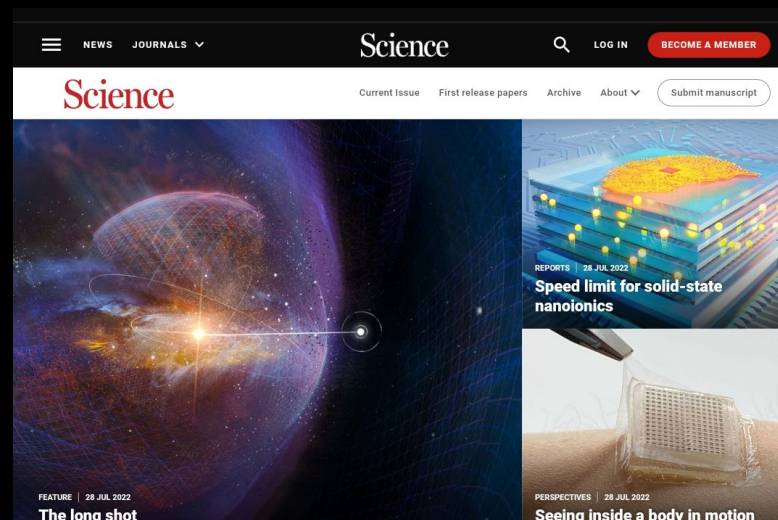
Science

July 29, 2022



M. Onen, et. al., Nanosecond Protonic Programmable Resistors for Analog Deep Learning, *Science*, (2022).

Highlighted on homepage



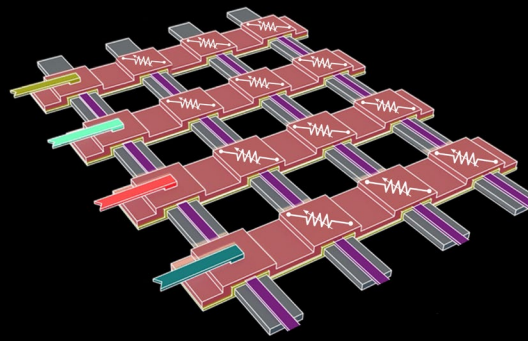
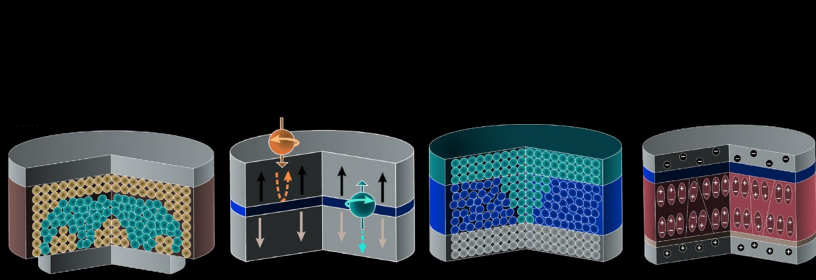
Press Coverage



THE NEW YORKER The New York Times

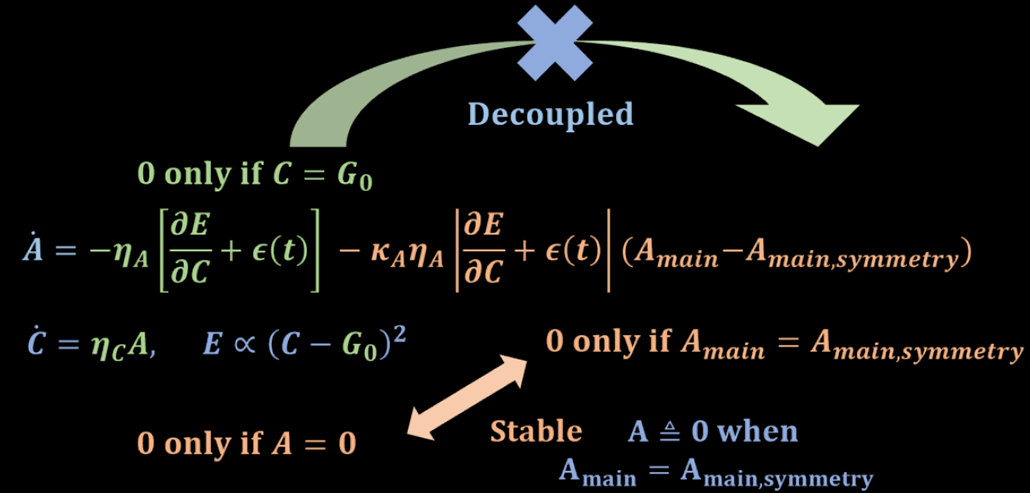
NEO.LIFE nature nanotoday

Interviews to be published



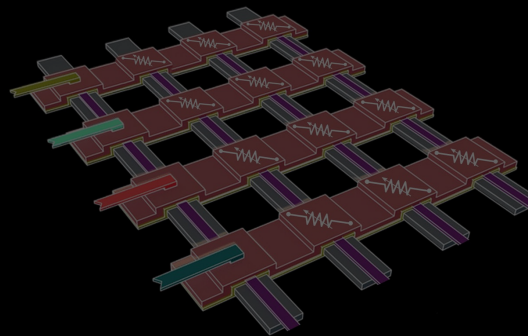
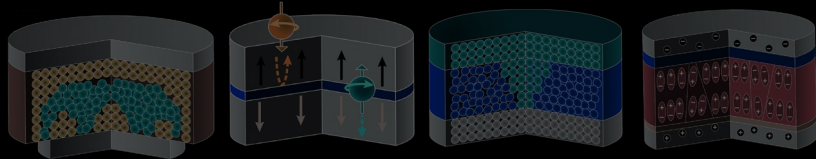
Devices

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- IV. $v = Au$
- V. $C \leftarrow C + \eta_C(u \times v)$



Hardware-aware training algorithms

Nonideality tolerance without compromising parallelism



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Stable $A \triangleq 0$ when $A_{\text{main}} = A_{\text{main, symmetry}}$

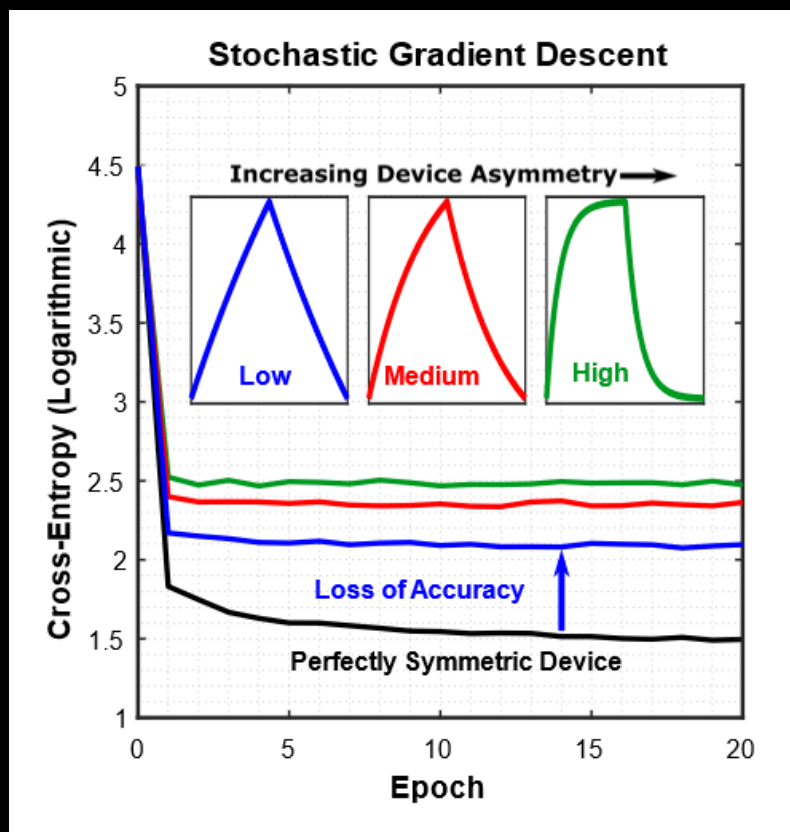
0 only if $C = G_0$

0 only if $A_{\text{main}} = A_{\text{main, symmetry}}$

0 only if $A = 0$

Devices

Algorithms



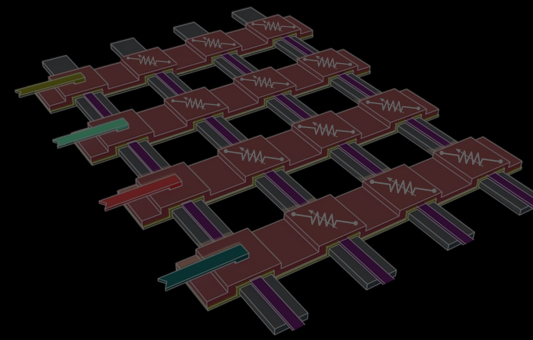
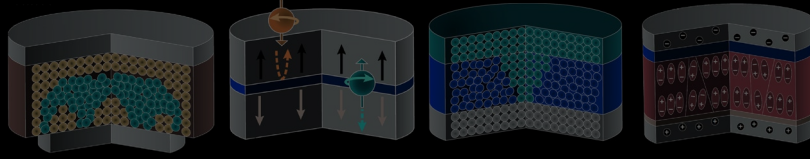
The Infamous Device Asymmetry

Proposed Solutions:

- ❖ Read-write-verify
- ❖ Weight carry
- ❖ Individual pulse-control
- ❖ Compliance circuitry
- ❖ Multiple device-copy

Sacrifices
parallelism

Sacrifices area &
energy-efficiency



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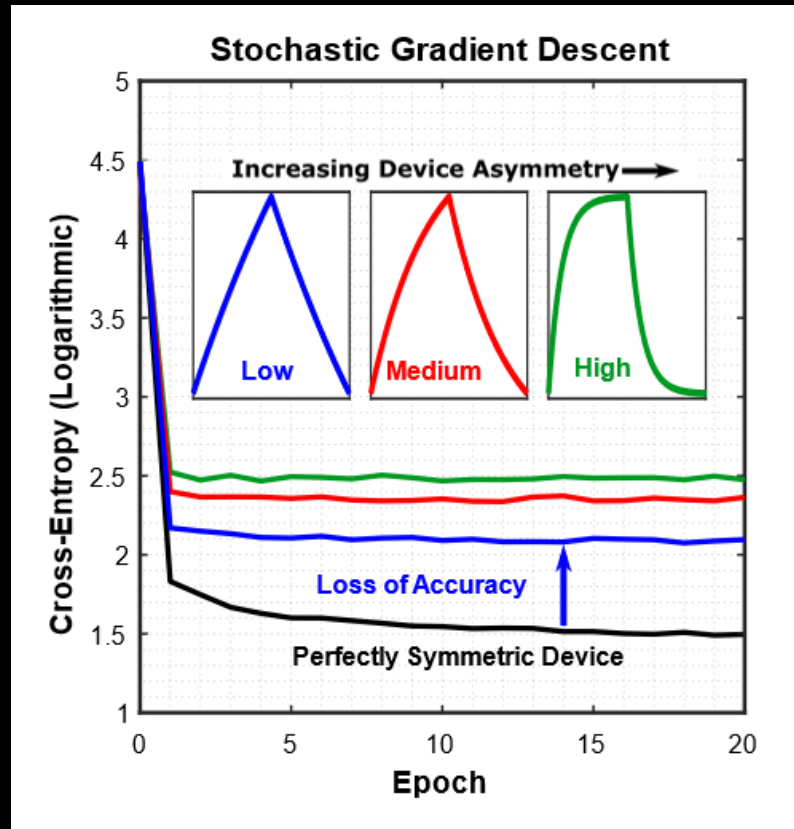
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Devices

Algorithms

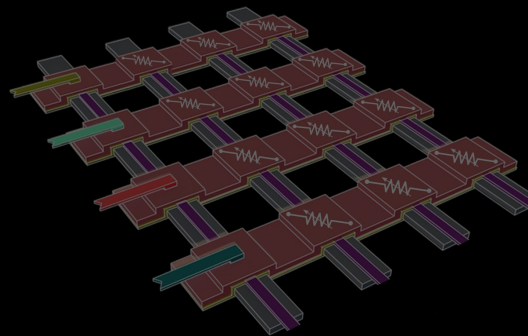
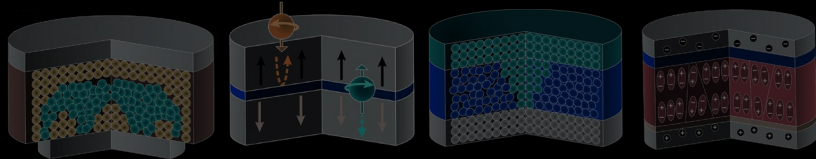


A More Fundamental Problem...

SGD Updates: Gradient of error (potential energy)
Points towards minima

Asymmetry: Error with each change (kinetic energy)
Points to the middle (competing minima!)

Incorporate hardware energy to the error function



Devices

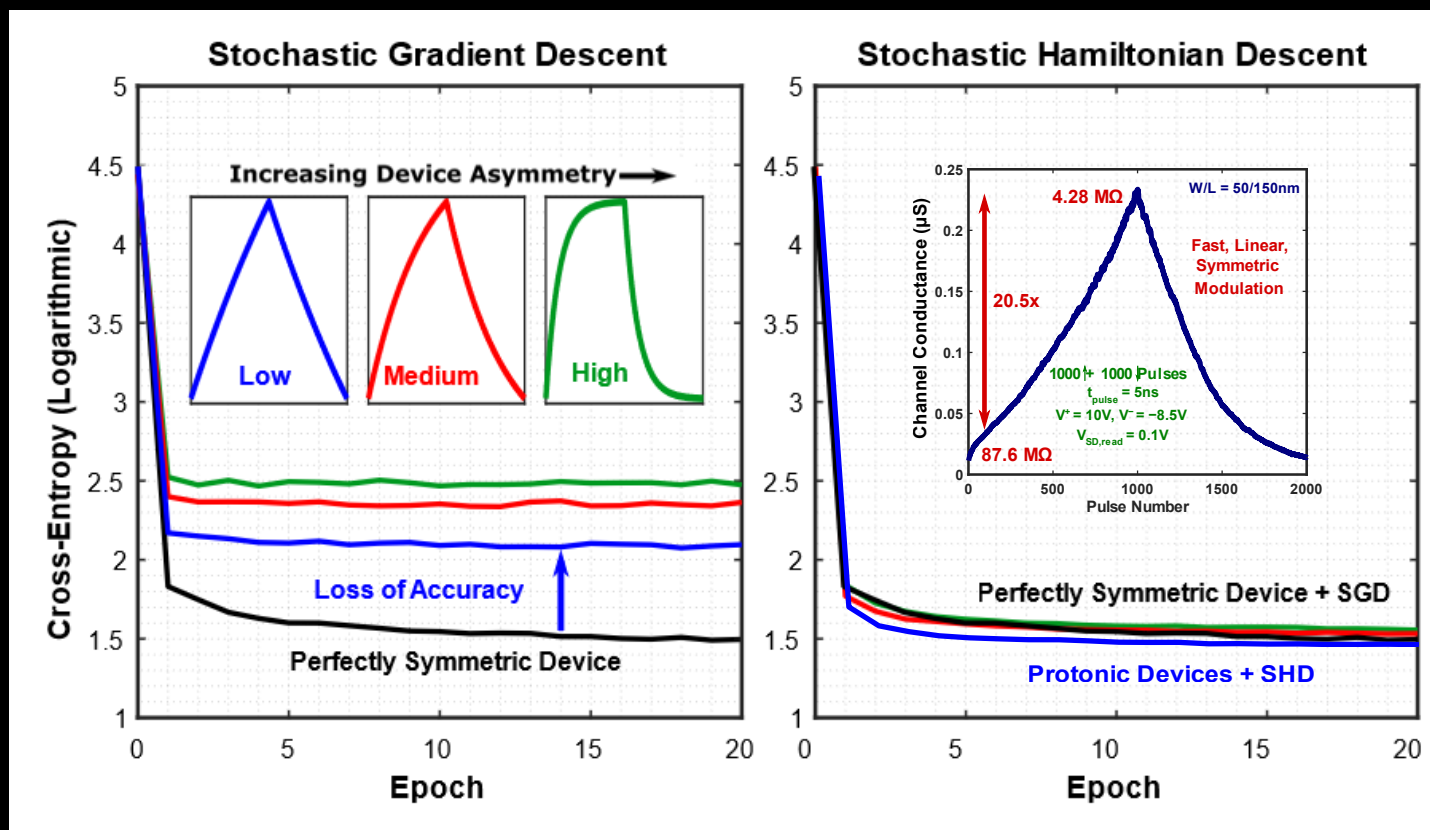
Algorithms

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Stable $A \triangleq 0$ when $A_{\text{main}} = A_{\text{main,symmetry}}$



Advanced Training Algorithm: SHD

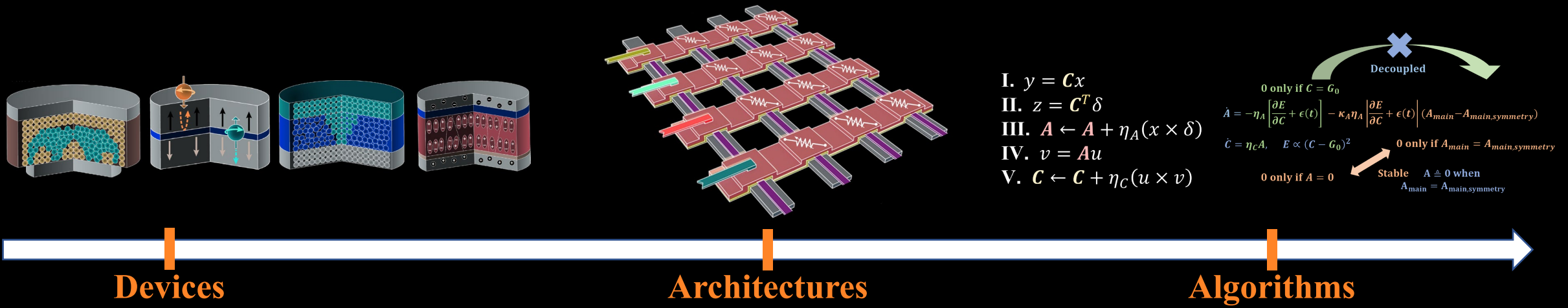
- ❖ Resolves infamous asymmetry penalty
- ❖ Preserves fully-parallel operation
- ❖ **SHD + protonic devices > SGD + "ideal"**

Intrinsic Processors: Beyond Deep Learning

- ❖ Matrix sketching & streaming
- ❖ Randomized numerical algorithms
- ❖ Generalized linear algebra

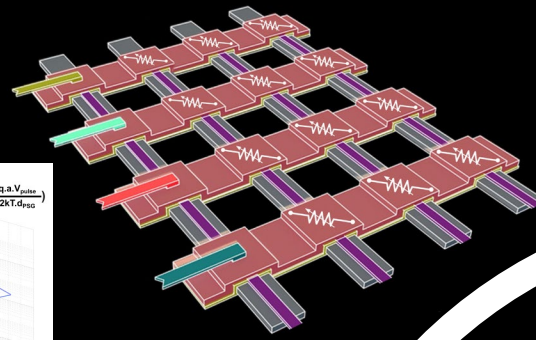
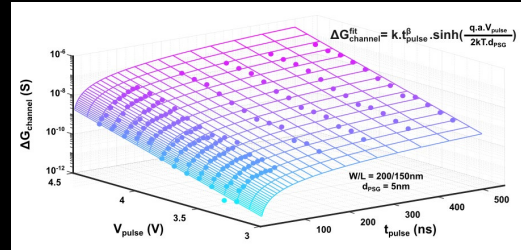
M. Onen, et. al., "Accelerated Quasi-Newton Methods on Analog Crossbar Hardware", Pending, US/2022/0083623.

M. Onen, et. al., "Matrix Sketching Using Analog Crossbar Architectures", Pending, US/2021/0357540, WO/2021/229320

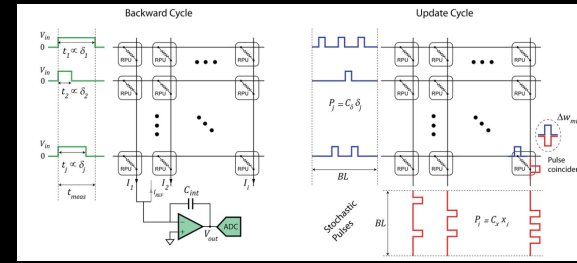


How to innovate faster?

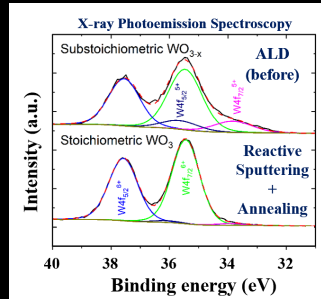
Co-optimization.



Efficient Architectures

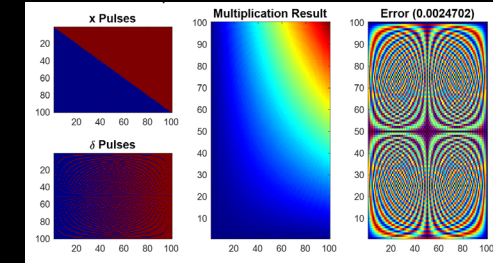


Circuit Optimization
System Pipelining
Analog-Digital Interfacing



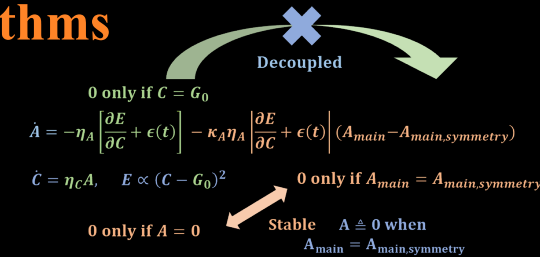
Material Science
Device Physics
Nanofabrication

Co-optimization.

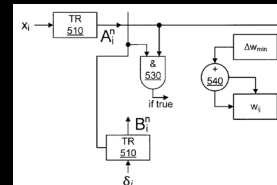
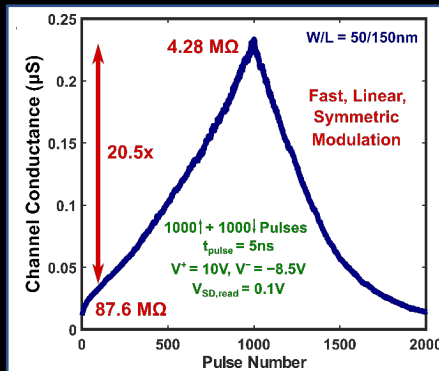
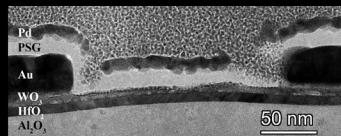
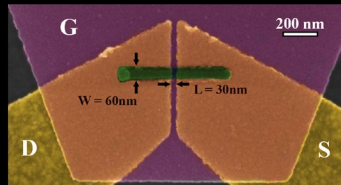


Analog-Specific Algorithms

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Optimal Devices

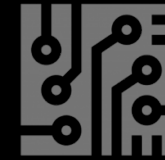


Device Modeling
Applied Mathematics
Fault-tolerant Computing

Devices and Algorithms for Analog Deep Learning

Presenter: Murat Onen
monen@mit.edu

Presented to:
Cambridge, MA
10/14/2022



MIT
AI Hardware
Program

Research Team: Jesús A. del Alamo
(devices) Bilge Yıldız
Ju Li
Frances M. Ross
Nicolas Émond
Baoming Wang
Difei Zhang

Research
Sponsor:



MIT-IBM
Watson
AI Lab

Acknowledgements:



Collaborators: Mantao Huang
Miranda Schwacke
Alexandre C. Foucher
Seungchan Ryu

Tayfun Gokmen
Malte Rasch
Lior Horesh
Wilfried Haensch

Teodor K. Todorov
Paul Solomon
Guy Cohen
John Rozen

Vasileios Kalantzis
Haim Avron
Seyoung Kim
Tomasz Nowicki